

MMK200T160UX

Thyristor -ELECTRICAL CHARACTERISTICS ($T_C=25^{\circ}\text{C}$ unless otherwise specified)

Symbol	Parameter/Test Conditions	Min.	Typ.	Max.	Unit
I_{DRM}	Maximum Peak Off-State Current $V_D = V_{DRM}, T_J = 125$			25	mA
I_{RRM}	Maximum Peak Reverse Current $V_R = V_{RRM}, T_J = 125$			25	mA
V_{TM}	Maximum on-state voltage drop I_{TM}				V
					V
					m
					V
					mA
					mA
					mA
					A
					V

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$I_{T(AV)}(A)$

P

Instantaneous Gate Voltage(V)

Instantaneous Gate Current(A)
Figure 11. SCR Gate Characteristics